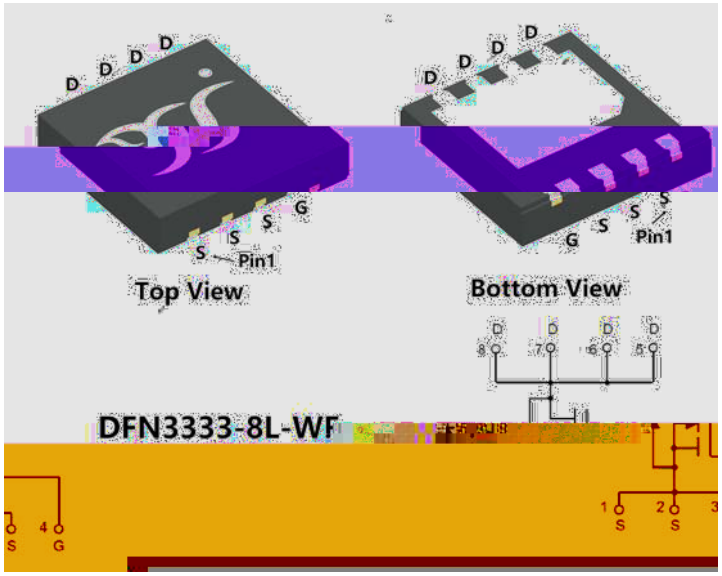
YJQ018G10AHQ

RoHS COMPLIANT

N-Channel Enhancement Mode Field Effect Transistor

Product Summary



General Description

Applications

Absolute Maximum Ratings

Parameter			Symbol	Limit	Unit
	p				

Thermal resistance

Parameter		Symbol	Typ	Max	Units

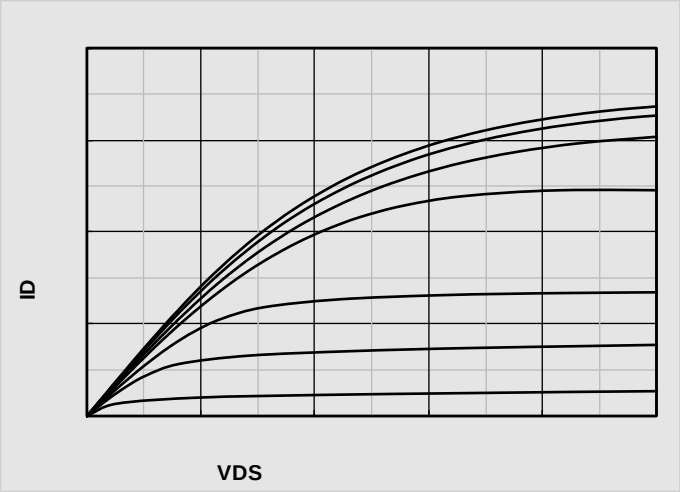
Ordering Information

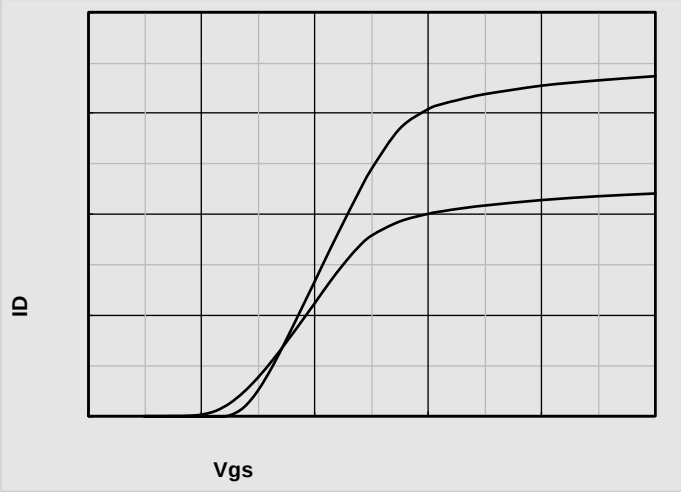
PREFERED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE

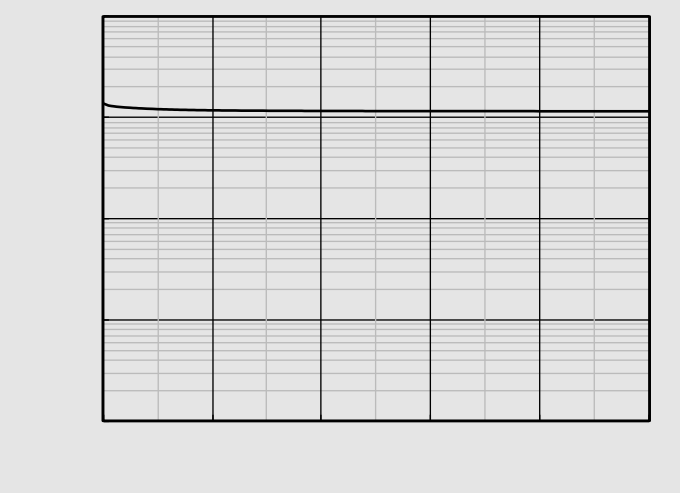
Electrical Characteristics

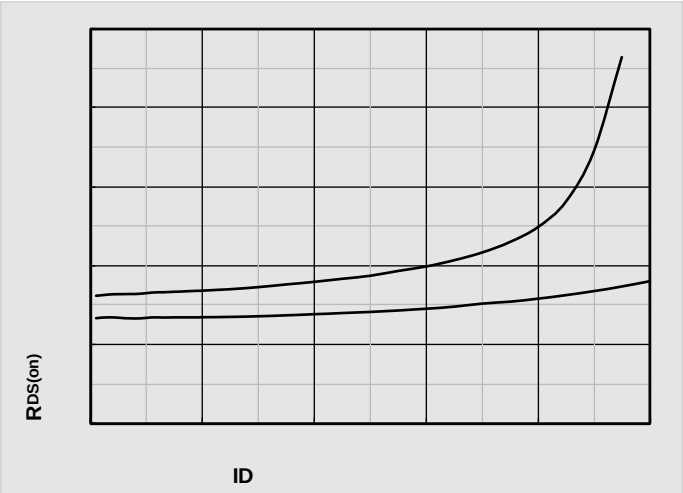
Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Dynamic Parameters						
Switching Parameters						

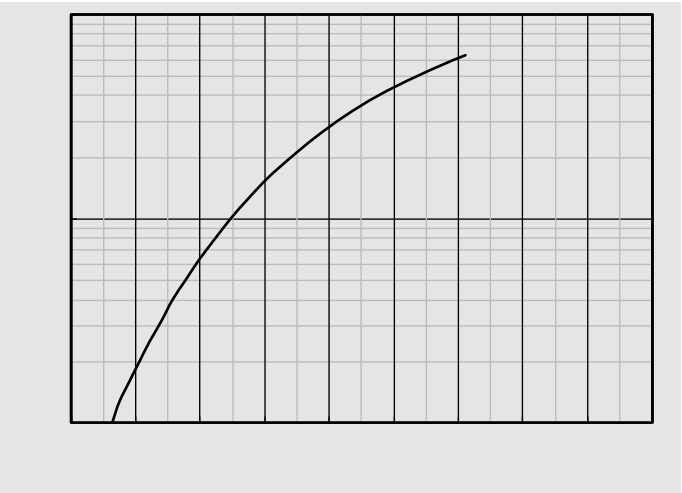
■Typical Electrical and Thermal Characteristics Diagrams

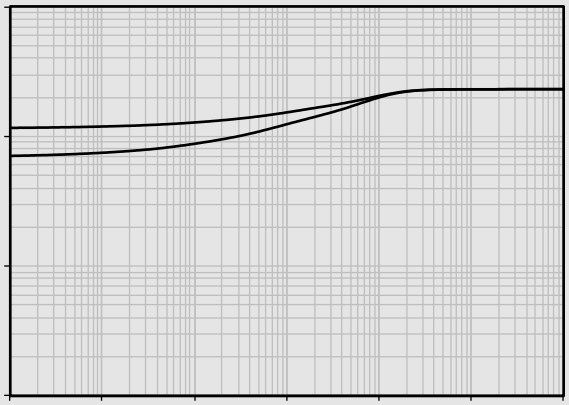


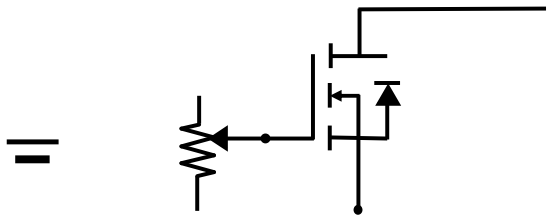




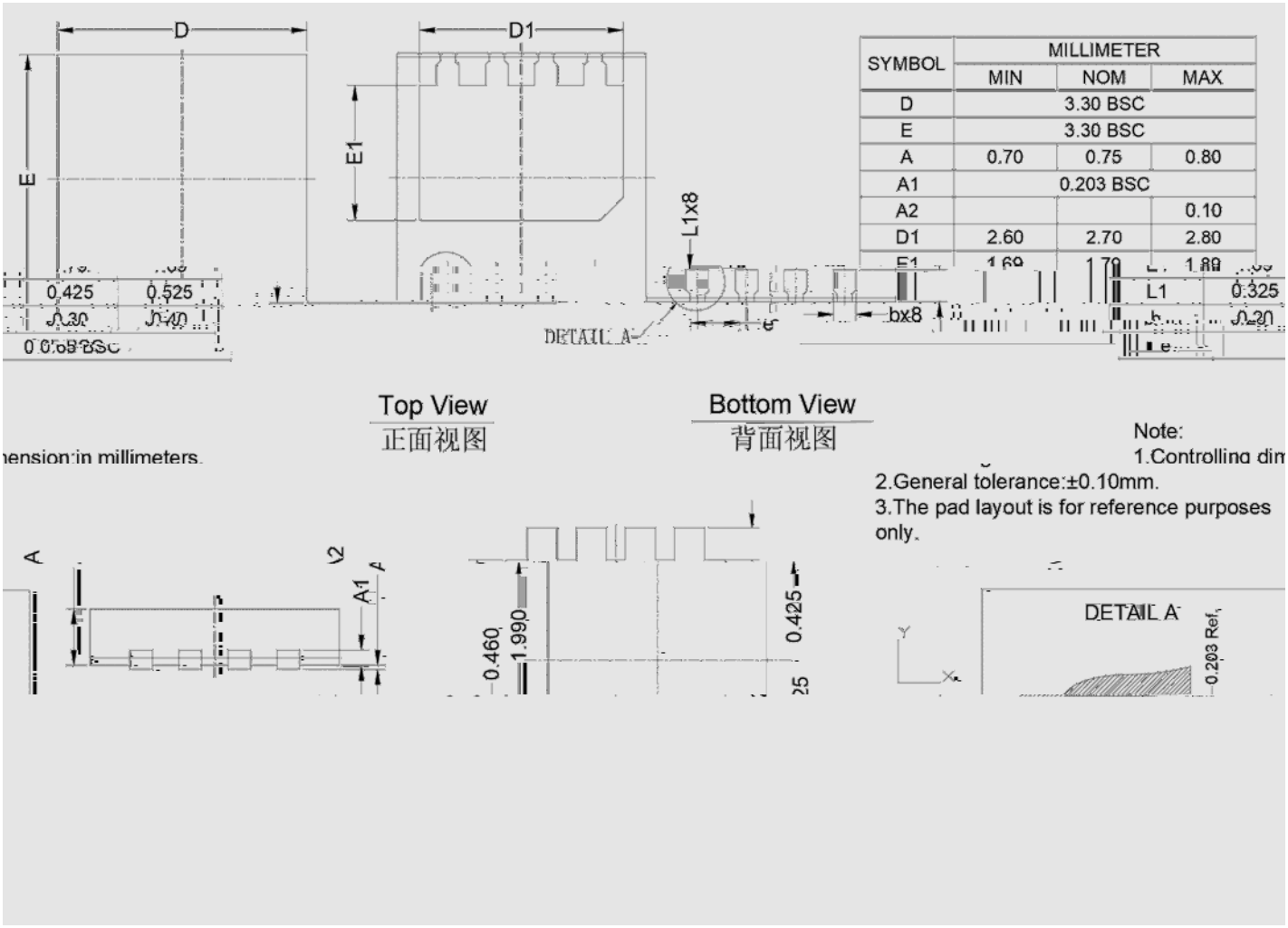

RDS(on)
ID







DFN3333-8L-WF Package information



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
D		3.30 BSC	
E		3.30 BSC	
A	0.70	0.75	0.80
A1		0.203 BSC	
A2			0.10
D1	2.60	2.70	2.80
E1	1.69	1.79	1.89

Disclaimer